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Doc. No. YOR920030077US1  
(YOR.449)

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re patent Application of:

Kam-Leung Lee, et al.

Serial No.: 10/627,753

Group Art Unit: 2823

Filing Date: July 28, 2003

Examiner: Brook Kebede

For: METHOD FOR SLOWING DOWN DOPANT-ENHANCED DIFFUSION IN  
SUBSTRATE AND DEVICES FABRICATED THEREFROM

Honorable Commissioner of Patents  
Alexandria, VA 22313-1450

**INFORMATION DISCLOSURE STATEMENT**

Sir:

Under the provisions of 37 CFR §1.97 through §1.99 and pursuant to Applicants' duty of disclosure under 37 CFR §1.56, Applicants respectfully bring the documents cited in the PCT International Search Report dated October 8, 2004, and listed on the attached form PTO-1449, to the attention of the Examiner in charge of the above-identified application. Copies of the listed documents are provided herewith for the convenience of the Examiner.

These citations do not constitute an admission that the references are relevant or material to the claims. They are only cited as constituting related art of which applicants are aware.

In compliance with the concise explanation requirement under 37 CFR § 1.98(a)(3) for foreign language documents, Applicants enclose herewith a copy of the PCT International Search Report citing such documents and indicating the degree of relevance found by the foreign office.

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I hereby certify that each item of information contained in this Information Disclosure Statement was the first citation of that item by a foreign patent office in a counterpart foreign application, which occurred not more than three months prior to the filing of this statement.

It is respectfully requested that the listed references be considered by the Examiner and formally made of record in this application.

Please charge any deficiencies in fees and credit any overpayment of fees to Assignee's Deposit Account No. 50-0510.

Respectfully submitted,

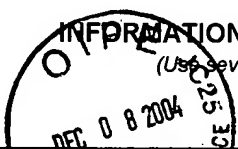
Date: December 8, 2004



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<div style="text-align: center;"> <b>INFORMATION DISCLOSURE CITATION</b>  <i>(Use several sheets if necessary)</i> </div> <div style="text-align: center; margin-top: 20px;">  </div>	ATTY DOCKET NO. <b>YOR920030077US1</b>	APPLICATION NO. <b>10/627,753</b>
	APPLICANT(S) <b>Kam-Leung Lee, et al.</b>	
	FILING DATE <b>July 28, 2003</b>	GROUP ART UNIT <b>2823</b>

<b>U.S. PATENT DOCUMENTS</b>
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*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
	6,518,150 B1	02/11/03	Matsumoto			
	6,069,062	05/30/00	Downey			
	6,180,476 B1	01/30/01	Yu			
	6,380,053 B1	04/30/02	Komatsu			

<b>U.S. PATENT APPLICATION PUBLICATIONS</b>
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*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
	2003/009640 A1	05/22/03	Borland, et al.			

<b>FOREIGN PATENT DOCUMENTS</b>
---------------------------------

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
							YES	NO

<b>OTHER DOCUMENTS</b> <i>(Including Author, Title, Date, Pertinent Pages, Etc.)</i>
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		Article by T.H. Huang, et al.: "Influence of Fluorine Preamorphization on the Diffusion and Activation of Low-Energy Implanted Boron During Rapid Thermal Annealing", Applied Physics Letters, American Institute of Physics, NY, US Vol. 65, No. 14, October 3, 1994, pp. 1829-1831.
		Article by S. Saito, et al.: "Defect Reduction by MeV ion Implantation for Shallow Junction Formation", Applied Physics Letters, American Institute of Physics, Vol. 63, No. 2, July 12, 1993, pp. 197-199.

<b>EXAMINER</b>	<b>DATE CONSIDERED</b>
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\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

<b>INFORMATION DISCLOSURE CITATION</b> <i>(Use several sheets if necessary)</i>				ATTY DOCKET NO. <b>YOR920030077US1</b>		APPLICATION NO. <b>10/627,753</b>	
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U.S. PATENT DOCUMENTS							
*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
		6,426,278 B1	07/30/02	Nowak, et al.			
		6,087,209	07/11/00	Yeap, et al.			
		6,410,393 B1	06/25/02	Hao, et al.			

U.S. PATENT APPLICATION PUBLICATIONS							
*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

FOREIGN PATENT DOCUMENTS								
		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
							YES	NO
		WO 97/42652	11/13/97	PCT				

OTHER DOCUMENTS <i>(Including Author, Title, Date, Pertinent Pages, Etc.)</i>			
			PCT International Search Report dated October 8, 2004.
			PCT Written Opinon of the International Searching Authority.

<b>EXAMINER</b>	<b>DATE CONSIDERED</b>
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